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User's Manual

External Flash Definition Editor

User's Manual

Renesas Electronics
www.renesas.com

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Introduction

The External Flash Definition Editor (hereafter referred to as the EFE) is the utility software to create the definition files that are needed to use the "external flash download function."

When you've created an external flash memory definition file with the EFE, register it in the emulator software that supports this function. That way, it becomes possible to use the external flash download function.

Abbreviations

Following abbreviations and abbreviated words are used in this manual.

Abbreviation/abbreviated word	Description
EFE	External Flash Definition Editor (this product)
RFD file	Renesas Flash Definition file (flash memory device definition files)
USD file	User System Definition file (user system definition files)
Emulator	Emulator systems made by Renesas
External flash memory	Flash memory devices connecting to a microprocessor's external bus
External flash download function	Function to download data into external flash memory
Write program	Program for writing to external memory
Standard program	Standard write program preinstalled in this product
JEDEC method	JEDEC standard command-compliant flash program method
CUI method	Intel/Sharp CUI command flash program method
HEW	High-performance Embedded Workshop, or the integrated development environment from Renesas

Manual Notation

Following notations are used in this manual.

Notation	Meaning
[item name]	Strings enclosed in [ ] represent the EFE GUI item names.
'parameter'	Strings enclosed in single quotes (') represent the parameters selected in the EFE GUI.
"string"	Strings enclosed in double quotes ("") represent the values set for each EFE GUI item.

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1. Summary

The flash memory devices connected externally to the external buses of a microprocessor are referred to as "external flash memory." Also, the function of an emulator system to download into or rewrite data in external flash memory is referred to as the "external flash download function."

The External Flash Definition Editor (hereafter referred to as the EFE) is the utility software to create the definition files that are needed to use the external flash download function.

When you've created an external flash memory definition file with the EFE, register it in the emulator software that supports this function. That way, it becomes possible to use the external flash download function.

1.1 Basic Composition

The EFE consists of the "editor body" and "standard program."

The "editor body" generates the following definition files in GUI-based software:

(1) Flash memory device definition file (RFD file)
Defines the specification of a flash memory device.

(2) User system definition file (USD file)
Defines how external flash memory will be used in a user system environment and includes a write program. It is this file that is registered in the emulator software.

The "standard program," preinstalled in this product, is a program for writing to flash memory.

The standard program is implemented by using the standard flash memory commands generally accepted for flash devices, and can therefore be used for most flash memory.

The standard program supports the following functions:

(1) JEDEC method
(2) CUI method
(3) Fast programming mode (write buffer programming and successive programming by UnlockBypass)
(4) Parallel connection of flash memory devices
(5) Program to flash after the lock bit is cleared

1.2 Position of the Product

The EFE is a common utility software independent of any specific emulator system.

Figure 1.1 schematically shows the position of the product in user systems.

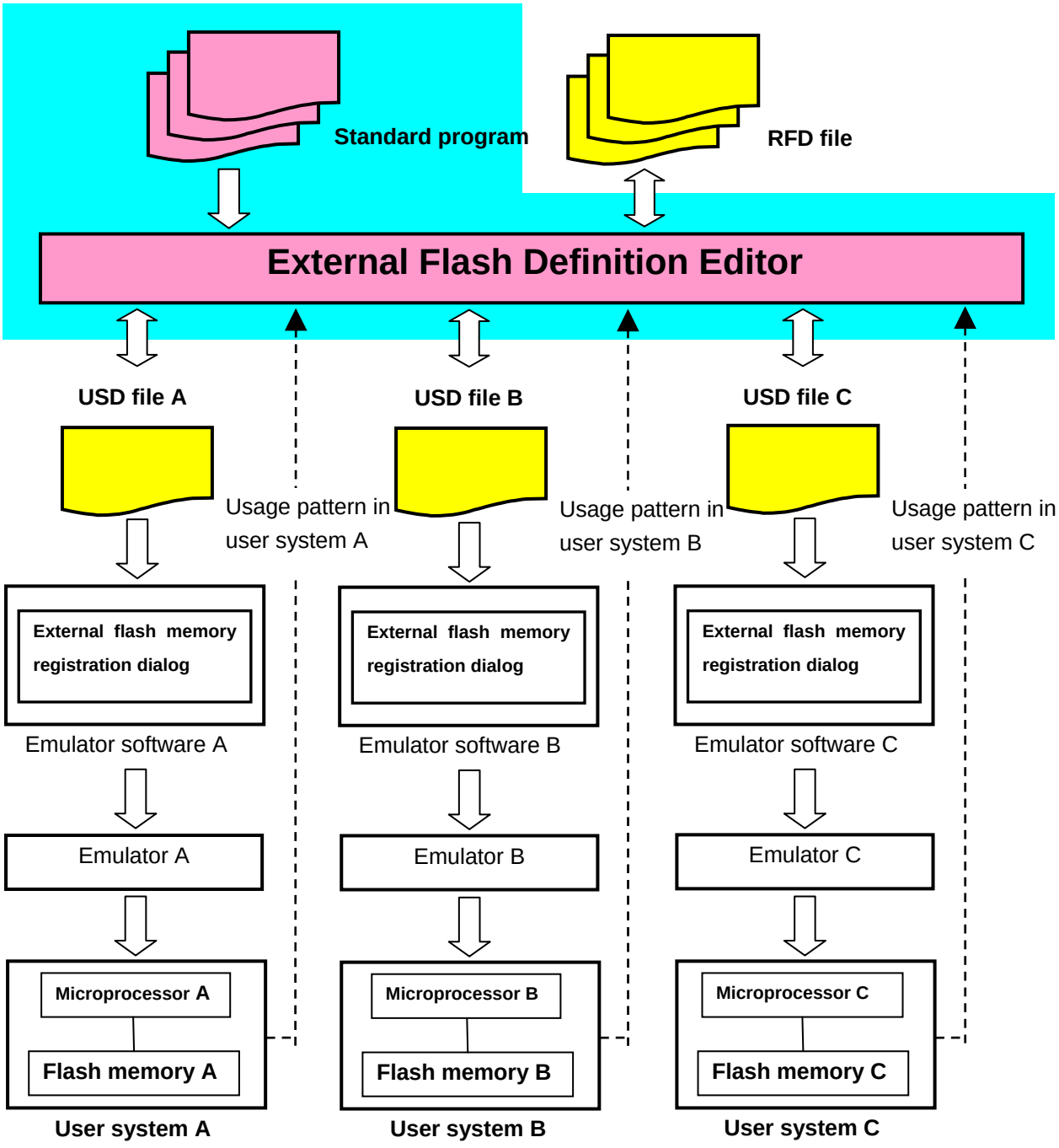


Figure 1.1 Position of the Product

1.3 Setup Procedure

1. Download the External Flash Definition Editor from the EFE product site.
2. Extract the downloaded file in any folder you want.
3. Launch EFE.exe in the extracted folder.

1.4 Folder Structure

Figure 1.2 shows the folder structure of this product.

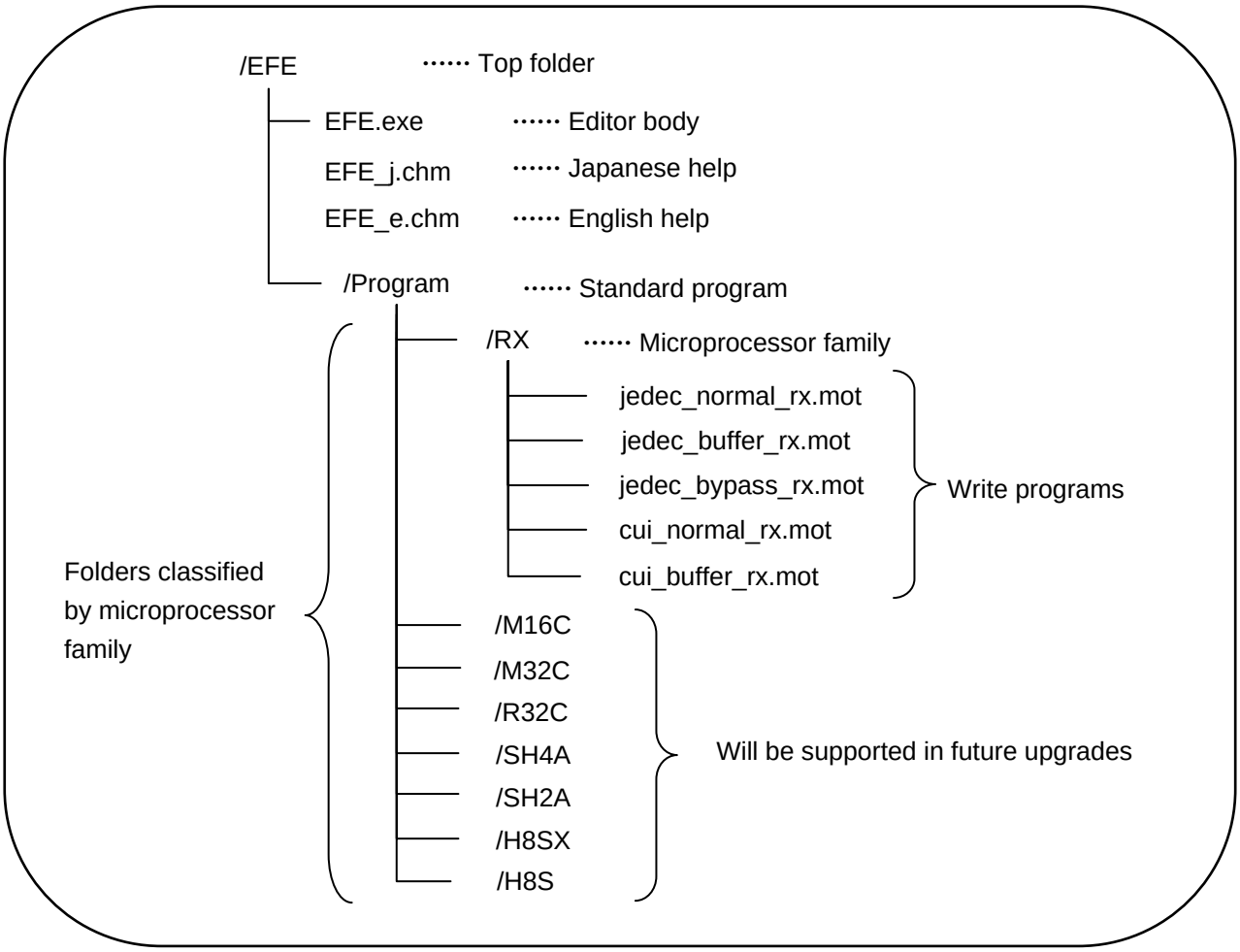


Figure 1.2 Folder Structure

1.5 Definition File Creation Flow

There are following two types of definition files that can be created with the EFE:

- RFD File (Renesas Flash Definition file)
- USD File (User System Definition file)

The RFD file is the one that defines the specification of the flash memory device used.
These files serve as input files for a USD file when it is created.

The USD file is the one that defines the manner of how flash memory will be used in a user system and the additional processing to be performed when programming to flash memory. The program used for writing to flash memory is included in this file.
By registering this file in the emulator software, it becomes possible to use the "external flash download function."

Figure 1.3 shows a flow of operations according to which definition files are generated.

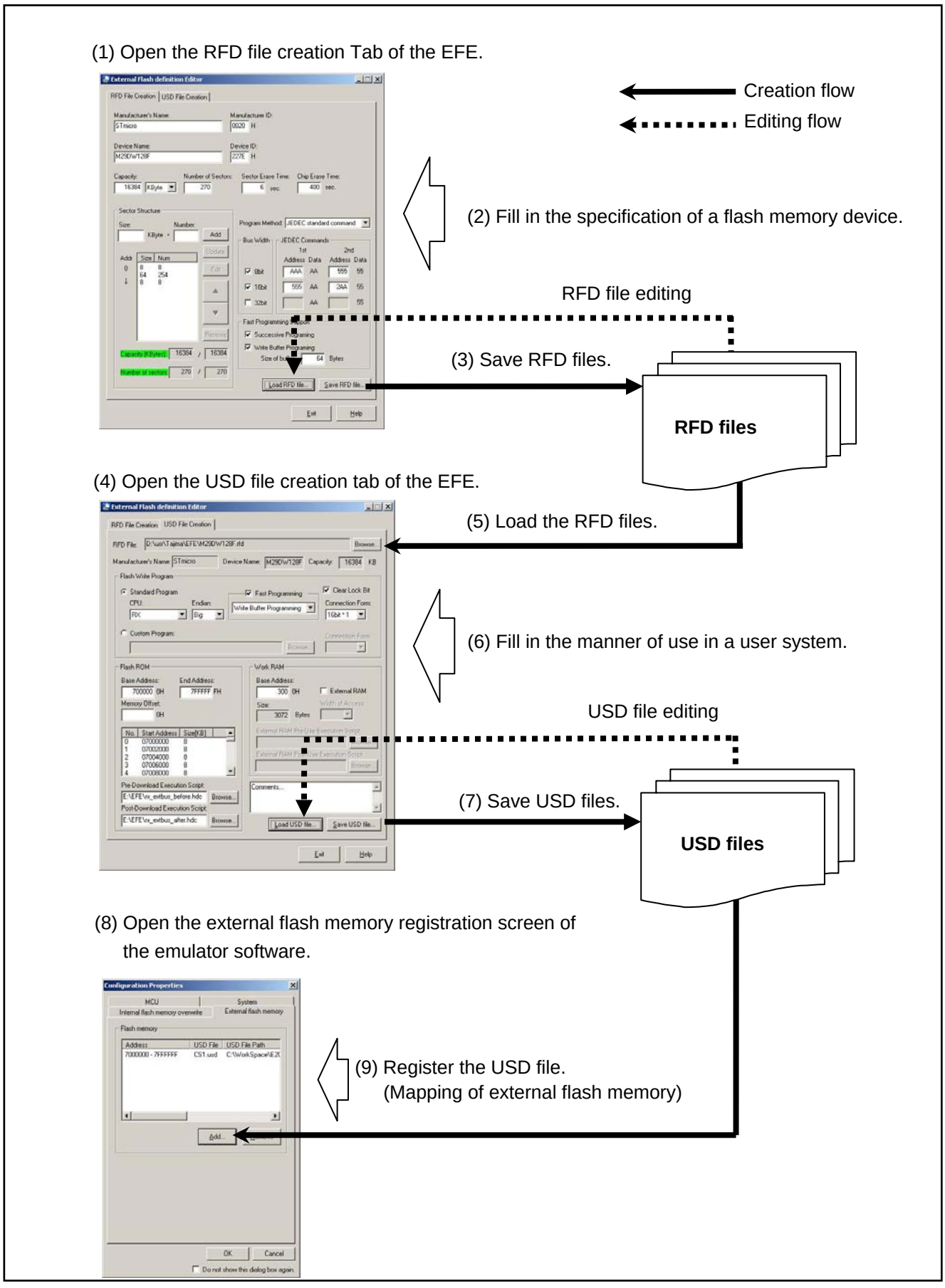

(1) Open the RFD file creation Tab of the EFE.
Creation flow
Editing flow
(2) Fill in the specification of a flash memory device.
RFD file editing
(3) Save RFD files.
RFD files
(4) Open the USD file creation tab of the EFE.
(5) Load the RFD files.
(6) Fill in the manner of use in a user system.
USD file editing
(7) Save USD files.
USD files
(8) Open the external flash memory registration screen of the emulator software.
(9) Register the USD file.
(Mapping of external flash memory)

Figure 1.3 Definition File Creation Flow

2. RFD File Creation Tab

On the RFD file creation tab, fill in the specification of a flash memory device to generate an RFD file. Before proceeding, please prepare a data sheet for the flash memory device you use.

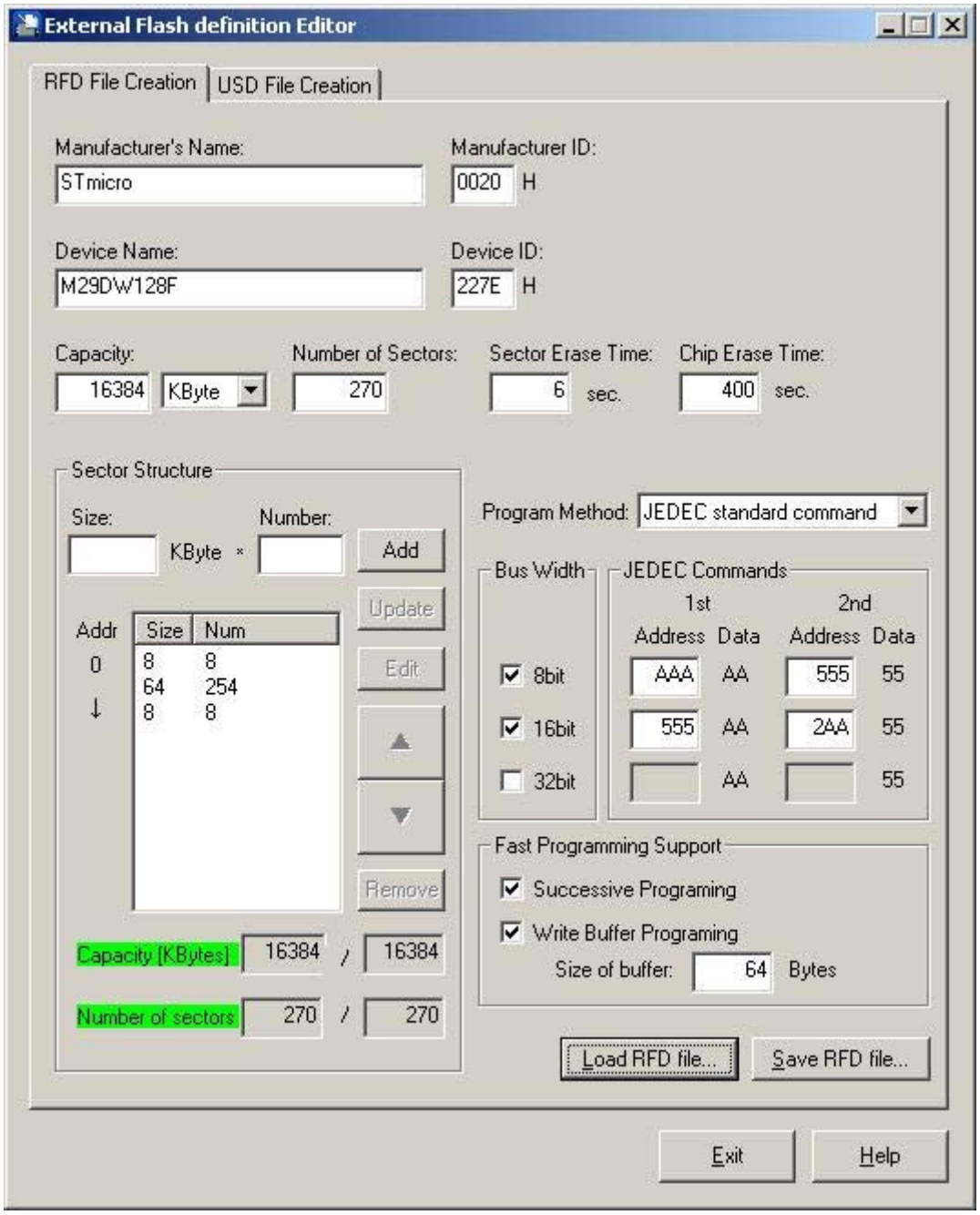


Figure 2.1 RFD File Creation Tab

2.1 Manufacturer's Name

Fill in the manufacturer's name of your flash memory device.

The manufacturer's name you enter here is displayed on screen when RFD files are loaded on the USD file creation tab.

2.2 Manufacturer ID

Fill in the manufacturer ID of your flash memory device.

The manufacturer ID, in the data sheet of each device manufacturer, may be stated as "maker ID," "maker code," "manufacturer ID," or "manufacturer code," for example.

Table 2.1 Examples of Manufacturer ID

Device manufacturer	Manufacturer ID	
	×8-bit device	×16-bit device
Spansion (AMD)	01h	0001h
Spansion (Fujitsu)	04h	0004h
Numonyx (STMicro electronics)	20h	0020h
Numonyx (Intel)	89h	0089h
Samsung	ECh	00ECh
Macronix	C2h	00C2h
Silicon Storage Technology	BFh	00BFh
Excel Semiconductor	4Ah	004Ah
Sharp	B0h	00B0h

Note: The above examples are shown for reference only.
Please be sure to consult the data sheet of your device manufacturer.

2.3 Device Name

Fill in the product type name of your flash memory device.

The product type name you enter here is displayed on screen when RFD files are loaded on the USD file creation tab.

2.4 Device ID

Fill in the device ID of your flash memory device.

The device ID, in the data sheet of each device manufacturer, may be stated as "device ID," "device code," "signature ID," or "signature code," for example.

Depending on the type of flash memory device concerned, the device ID may consist of multiple words.

In such a case, enter only the first word of a device ID.

For example, if the ID of your flash memory device is stated as follows in its data sheet, then enter "227E."

Table 2.2 Example of Entering a Device ID (1)

DEVICE CODE: 227Eh + 2220h + 2200h

Also, for flash memory devices whose data bus width is switchable, the device ID may be stated separately by bus width. In that case, enter the value given for the larger bus width than the other.

For example, if the ID of your flash memory device is stated as follows in its data sheet, then enter "1234."

Table 2.3 Example of Entering a Device ID (2)

	8-bit mode		16-bit mode	
	DQ15-DQ8	DQ7-DQ0	DQ15-DQ8	DQ7-DQ0
DEVICE CODE	Hi-Z	34h	12h	34h

2.5 Capacity

Enter the memory capacity in Kbyte or Mbyte units.

For memory capacities, the following applies:

1 Kbyte = 1,024 bytes

1 Mbyte = 1,024 Kbytes

For example, if the capacity of your flash memory device is stated as

128 Mbits (16 Mb × 8 or 8 Mb × 16)

then enter "16" [Mbyte] or "16384" [Kbyte].

2.6 Number of Sectors

Enter the aggregate number of sectors in your flash memory device.

For even flash memory devices whose sector sizes are irregular, enter simply the number of sectors, irrespective of the difference in sizes of individual sectors.

2.7 Sector Erase Time

Enter the maximum sector erase time in seconds. Fractional digits after the decimal point can also be entered.

2.8 Chip Erase Time

Enter the maximum erase time of the entire chip in seconds.

2.9 Sector Structure

Figure 2.2 shows the composition of the sector structure group of the editor screen.

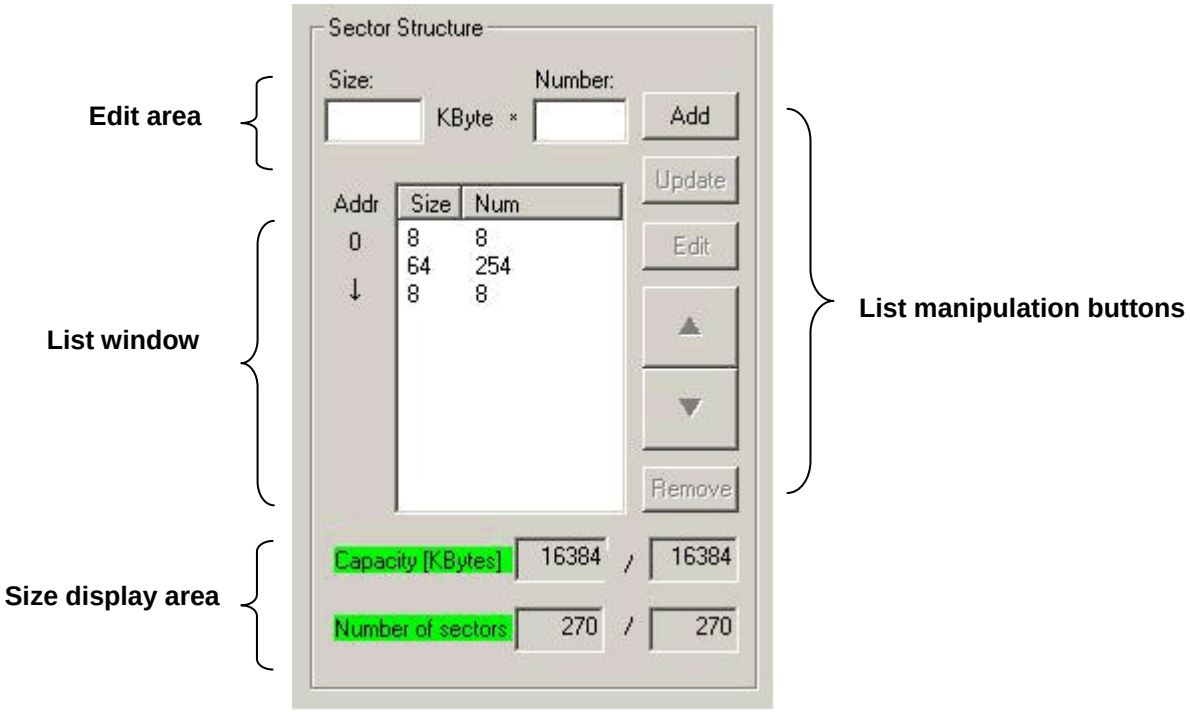


Figure 2.2 Sector Structure Group

2.9.1 Edit Area

Enter the sector structure of your flash memory device in the form "size of one sector × number of consecutive sectors."

When you click the [Add] or the [Update] button, the contents you've entered are reflected in the list window.

Until you finish defining the entire sector structure of your flash memory device in the list window, add list lines from here.

2.9.2 List Manipulation Buttons

These buttons permit you to manipulate the list.

[Add] button	Adds the content of the edit area to the list window. If any line in the list window is selected, the content is inserted into a place above the selected line. If no lines are selected, the content is inserted into the bottom line of the list.
[Update] button	Replaces the content of a selected line with that of the edit area.
[Edit] button	Shows the content of a selected line of the list window in the edit area.
[▲] button	Moves a selected line one line up in the list to change places.
[▼] button	Moves a selected line one line down in the list to change places.
[Remove] button	Removes a selected line from the list window.

2.9.3 List Window

Shows the sector structure you've entered in list form.

Each line in the list is selected when you click on it, allowing you to perform any operation on it using the list manipulation button.

Be sure the list is aligned in order of ascending memory addresses, from top to bottom of the list window.

For flash memory devices that have a sector structure like the one in Table 2.4, for example, set up the list as in Figure 2.3.

Table 2.4 Example of a Sector Structure

No	Size [KByte]	Address Range (×8)		No	Size [KWord]	Address Range (×16)
0	64	1F0000h-1FFFFFh		0	32	0F8000h-0FFFFFh
1	64	1E0000h-1EFFFFh		1	32	0F0000h-0F8FFFh
2	64	1D0000h-1DFFFFh		2	32	0E8000h-0F0FFFh
. . .	. . .	. . .		. . .	. . .	. . .
28	64	030000h-03FFFFh	64KB×31	28	32	018000h-01FFFFh
29	64	020000h-02FFFFh		29	32	010000h-017FFFh
30	64	010000h-01FFFFh		30	32	008000h-00FFFFh
31	32	008000h-00FFFFh	32KB×1	31	16	004000h-007FFFh
32	8	006000h-007FFFh	8KB×2	32	4	003000h-003FFFh
33	8	004000h-005FFFh		33	4	002000h-002FFFh
34	16	000000h-003FFFh	16KB×1	34	8	000000h-001FFFh

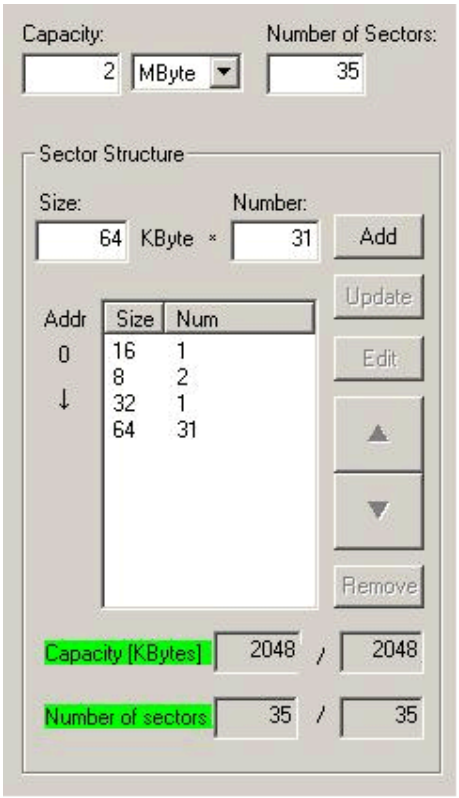


Figure 2.3 Example of Setting Up the List Window

2.9.4 Size Display Area

After calculating the entire memory capacity of the list and the number of sectors in the list window, it shows the result in the form shown below.

Capacity [Kbytes]: Total memory capacity of list lines / aggregate memory capacity
Number of sectors: Total number of sectors of list lines / aggregate number of sectors

The aggregate memory capacity and the aggregate number of sectors here show the values you've set in Section 2.5, "Capacity," and Section 2.6, "Number of Sectors," respectively.

The total memory capacity of list lines and the total number of sectors of list lines are automatically recalculated and redisplayed each time the list is updated.
When the left and right values of either item match, the color of the item name changes to green, showing an agreement with the expected value.
Conversely, if the left-side value of either item exceeds its right-side value, the color of the item name changes to red, showing that the input value does not agree.

When the entire sector structure is entered correctly, Capacity [Kbytes] and Number of Sectors both are displayed in green.

2.10 Program Method

For the program method, select either 'JEDEC standard command method' or 'CUI command method'.

2.11 Supported Bus Width

Put a check mark in the appropriate checkbox for the data bus width supported by your flash memory device.
If your flash memory device is a type that permits the bus width to be switched by pin control, put a check mark in all of the supported bus width checkboxes.

For example, if the data sheet of your flash memory device stipulates its bus width as follows

128 Mbit (16 Mb × 8 or 8 Mb × 16)

then check the bus width checkboxes as shown below.

Figure 2.4 Example of Setting Up the Supported Bus Width

2.12 JEDEC Commands

Set the command address pattern used in the JEDEC method.

When you put a check mark in the supported bus width checkbox, the default command address pattern is displayed.

For almost all flash memory devices, these default settings do not need to be altered without causing any problem. However, products from some device manufacturers require different settings.

In that case, alter the values of the default command address pattern according to the contents stipulated in the product data sheet.

2.13 Fast Programming Support

If your flash memory device supports the fast programming mode, put a check mart in the appropriate checkbox.

For the JEDEC method, you can check the [Successive Programming] and [Write Buffer Programming] checkboxes. If both of these methods are supported, put a check mark in both checkboxes.

For the CUI method, you can check only the [Write Buffer Programming] checkbox.

If you've checked [Write Buffer Programming], enter the write buffer size in byte units which is internally available in your flash memory device.

Figure 2.5 shows, when the JEDEC method selected, an example of how to specify for a flash memory device that supports both [Successive Programming] and [Write Buffer Programming].

Figure 2.5 Example of Specifying Fast Programming Support

■ Successive Programming (JEDEC method)

Table 2.5 Successive Programming (JEDEC method)

Command	mode	1st		2nd		3rd	
		addr	data	addr	data	addr	data
Unlock Bypass Entry	16bit	555h	AAh	2AAh	55h	555h	20h
	8bit	AAAh	AAh	555h	55h	AAAh	20h
Unlock Bypass Program	-	X	A0h	PA	PD	-	-
Unlock Bypass Reset	-	X	90h	X	00h	-	-

* PA: Program Address

* PD: Program Data

■ Write Buffer Programming (JEDEC method)

Table 2.6 Write Buffer Programming (JEDEC method)

Command	mode	1st		2nd		3rd		4th		5th		6th	
		addr	data	addr	data	addr	data	addr	data	addr	data	addr	data
Write to Buffer and Program	16bit	555h	AAh	2AAh	55h	BA	25h	BA	N	PA	PD	BA	29h
	8bit	AAAh	AAh	555h	55h	BA	25h	BA	N	PA	PD	BA	29h

* BA: Block Address (sector address)
* N: Number of Words to be programmed - 1
* PA: Program Address
* PD: Program Data

■ Write Buffer Programming (CUI method)

Table 2.7 Write Buffer Programming (CUI method)

Command	1st		2nd		3rd		4th	
	addr	data	addr	data	addr	data	addr	data
Write to Buffer and Program	BA	E8h	BA	N	PA	PD	X	D0h

* BA: Block Address (sector address)
* N: Number of Words to be programmed - 1
* PA: Program Address
* PD: Program Data

2.14 Load RFD File

To edit the RFD file you've created or create a new RFD file based on the RFD file you've created, specify the source RFD file here that you want to edit or from which to create.

2.15 Save RFD File

This button saves the RFD file.

If the input content of the file is incomplete or erroneous, an error message is output and the save operation is canceled. In that case, correct the content according to the instructions of the error message.

3. USD File Creation Tab

On the USD file creation tab, you create a USD file that defines the manner of how your flash memory will be used.

By registering a USD file in the emulator software, you'll have your flash memory device recognized as external flash memory.

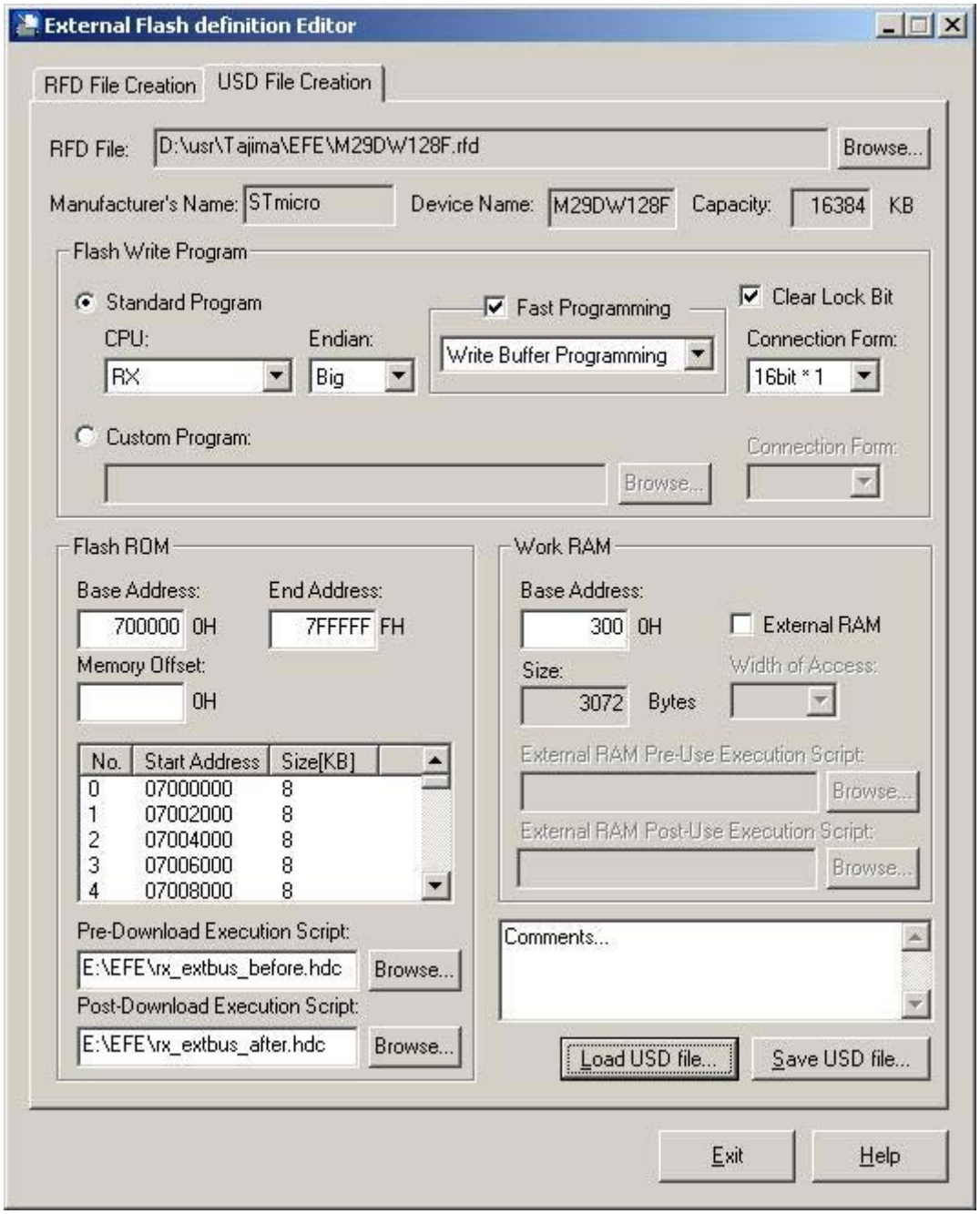


Figure 3.1 USD File Creation Tab

3.1 Referring to the RFD File

Specify the RFD file to be referred to.

To create a new USD file, you first need to specify the appropriate RFD file here.

Of the loaded information, three items of information—[Manufacturer Name], [Device Name], and [Capacity]—are displayed in the area below this box.

3.2 Flash Write Program

This group of the dialog is used to set a program for writing to flash memory.

3.2.1 Selecting a Write Program

Select the type of write program you want to use for program to flash memory.

■ Standard Program

Selecting this radio button uses the standard program preinstalled in this product.

The standard program is written using the standard flash memory commands supported by every device manufacturer, and can therefore be used for the majority of flash memory devices.

For the options available when [Standard Program] is selected, see Sections 3.2.2 through 3.2.6.

■ Custom Program

For flash memory devices for which the standard program is not usable, select this radio button.

In this case, you specify a write program you've prepared yourself.

For the options available when [Custom Program] is selected, see Sections 3.2.7 through 3.2.8

3.2.2 CPU

Choose the CPU type of your microprocessor from the pulldown menu.

3.2.3 Endian

For bi-endian microprocessors, specify the appropriate endian that suits the working environment.

For endian-fixed microprocessors, Endian is automatically displayed.

3.2.4 Fast Programming

To execute programs to flash memory in fast programming mode, check this checkbox.

You can select this checkbox when your flash memory device supports one or both of the following programming modes.

If you cannot program normally in fast programming mode, deselect this checkbox.

■ Write Buffer Programming

This programming mode is provided for flash memory devices that have write buffer memory.

Data is transferred one word in one bus cycle.

■ Successive Programming

This mode can be specified for only the JEDEC method.

With part of program commands omitted, data is transferred one word in two bus cycles.

3.2.5 Clear Lock Bit

If you want to program to flash memory after clearing the lock (protect) bits set for its sectors, check this checkbox. Note that the editor does not perform a relock process after completion of the program operation.

■ JEDEC method

The commands listed in Table 3.1 are used to clear the lock bits.

Table 3.1 Lock Set/Clear Commands when JEDEC Method is selected

	1st		2nd		3rd		4th	
	addr	data	addr	data	addr	data	addr	data
Set Lock bit	555h	00AAh	2AAh	0055h	555h	0048h	BA	XX01h
Clear Lock bit	555h	00AAh	2AAh	0055h	555h	0048h	BA	XX00h

* BA: Block Address (sector address)

* These locks are effective only during the 16-bit mode. Therefore, these locks are effective only when the flash memory is connected in the [16-bit × 1] or [16-bit × 2] form.

* The command names may not always be expressed as "Set Lock bit" and "Clear Lock bit" depending on device manufacturers.

■ CUI method

The commands listed in Table 3.2 are used to clear the lock bits.

Table 3.2 Lock Set/Clear Commands when CUI Method is selected

	1st		2nd	
	addr	data	addr	data
Block Protect	XXh	60h	BA	01h
Block Unprotect	XXh	60h	XXh	D0h

* BA: Block Address (sector address)

* When Block Unprotect is executed, the lock of the entire chip is unlocked.

* The command names may not always be expressed as "Block Protect" and "Block Unprotect" depending on device manufacturers.

3.2.6 Connection Form (Standard Program)

Specify the form of connection between the microprocessor and flash memory.

From the pulldown menu list, select the connection form that suits your working environment.

The list shows only the usable connection forms as determined from the flash memory used and the currently selected CPU.

The meaning of each displayed form of connection is as follows:

(1) 8bit × 1: One flash memory device in data bus width of 8 bits is connected. Therefore, the data bus is 8 bits wide.

(2) 8bit × 2: Two flash memory devices in data bus width of 8 bits are connected in parallel. Therefore, the data bus is 16 bits wide.

(3) 8bit × 4: Four flash memory devices in data bus width of 8 bits are connected in parallel. Therefore, the data bus is 32 bits wide.

(4) 16bit × 1: One flash memory device in data bus width of 16 bits is connected. Therefore, the data bus is 16 bits wide.

(5) 16bit × 2: Two flash memory devices in data bus width of 16 bits are connected in parallel. Therefore, the data bus is 32 bits wide.

(6) 32bit × 1: One flash memory device in data bus width of 32 bits is connected. Therefore, the data bus is 32 bits wide.

Figure 3.2 shows the relationships between the connection forms and aggregate memory capacities in respective cases where 1 MB (data 8 bits wide), 1 MB (data 16 bits wide), and 1 MB (data 32 bits wide) flash memory devices are connected.

(1) 8bit×1

D7-D0
00000
00001
.
.
.
.
FFFFE
FFFFF

Total 1MB

(2) 8bit×2

D15-D8	D7-D0
000001	000000
000003	000002
.	.
.	.
.	.
.	.
1FFFFD	1FFFFC
1FFFFF	1FFFFE

Total 2MB

(3) 8bit×4

D31-D24	D23-D16	D15-D8	D7-D0
000003	000002	000001	000000
000007	000006	000005	000004
.	.	.	.
.	.	.	.
.	.	.	.
.	.	.	.
3FFFFB	3FFFFA	3FFFF9	3FFFF8
3FFFFF	3FFFFE	3FFFFD	3FFFFC

Total 4MB

(4) 16bit×1

D15-D8	D7-D0
00001	00000
00003	00002
.	.
.	.
FFFFD	FFFFC
FFFFF	FFFFE

Total 1MB

(5) 16bit×2

D31-D24	D23-D16	D15-D8	D7-D0
000003	000002	000001	000000
000007	000006	000005	000004
.	.	.	.
.	.	.	.
1FFFFB	1FFFFA	1FFFF9	1FFFF8
1FFFFF	1FFFFE	1FFFFD	1FFFFC

Total 2MB

(6) 32bit×1

D31-D24	D23-D16	D15-D8	D7-D0
00003	00002	00001	00000
.	.	.	.
FFFFF	FFFFE	FFFFD	FFFFC

Total 1MB

Figure 3.2 Relationships between the Connection Forms and Aggregate Memory Capacities

3.2.7 Specifying a Custom Program Path

Specify a file path to the custom program.
The custom program must meet the following requirements:

- File format Motorola S format
- Code size 8,192 bytes or less
- Endian For bi-endian CPUs, it is necessary that the program be compiled using little-endian format, irrespective of its run-time CPU endian.
  (Endian conversions executed in the emulator software)
- Write buffer programming
  Write to buffer 256 bytes or less.

When you create a custom program, see the separately supplied sample program for reference.

3.2.8 Connection Form (Custom Program)

Specify the form of connection between the microprocessor and flash memory.
From the pulldown menu list, select the connection form that suits your usage conditions.
The meaning of each displayed form of connection is the same as in Section 3.2.6.

3.3 Flash ROM

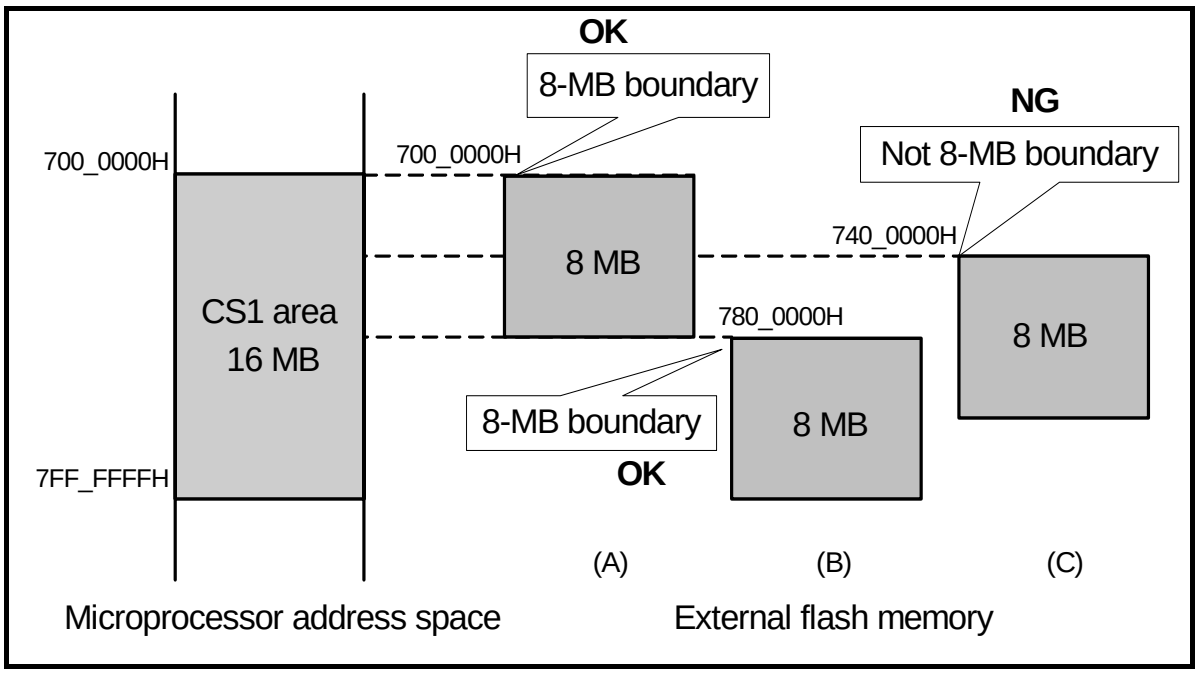
Specify the address mapping of flash memory and the command script automatically issued before and after a download.

3.3.1 Base Address

Set the mapping start address of the flash memory.

Specify the address boundary that matches the flash memory size.

However, if you specify [Memory Offset] here there is no need to specify it.



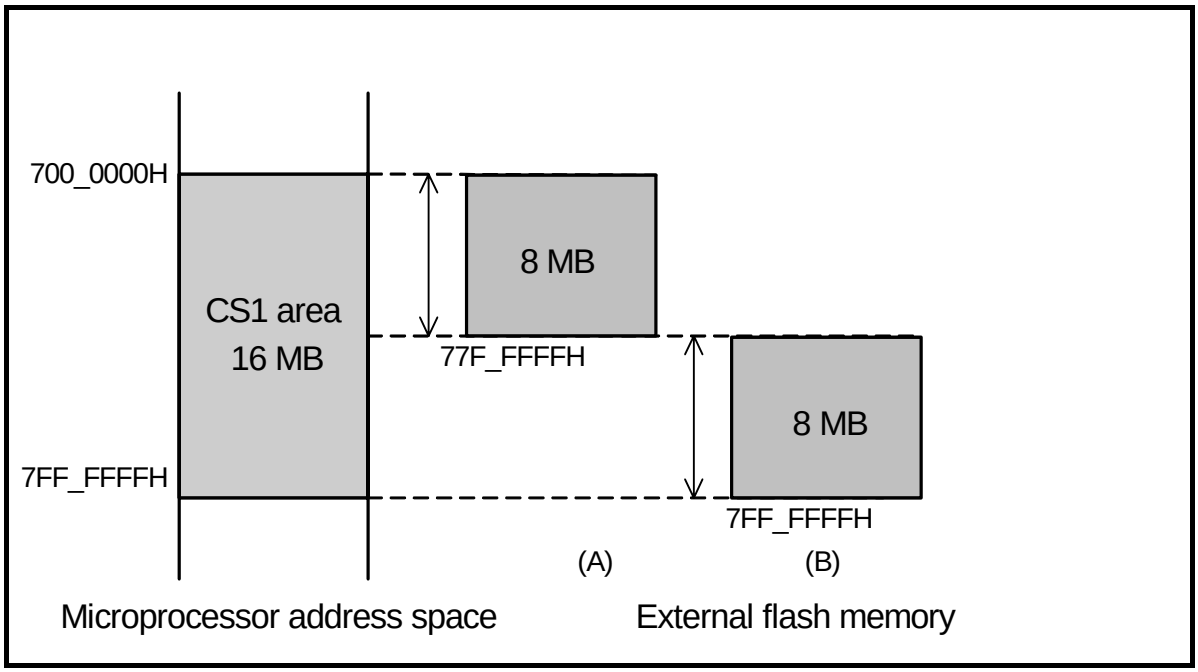
* Example for the case where 8-MB flash memory devices are mapped to the CS1 area by the RX610

Figure 3.3 Example of Setting the Base Address

3.3.2 End Address

Set the mapping end address of the flash memory.

Normally, set (base address + flash memory size – 1).



* Example for the case where 8-MB flash memory devices are mapped to the CS1 area by the RX610

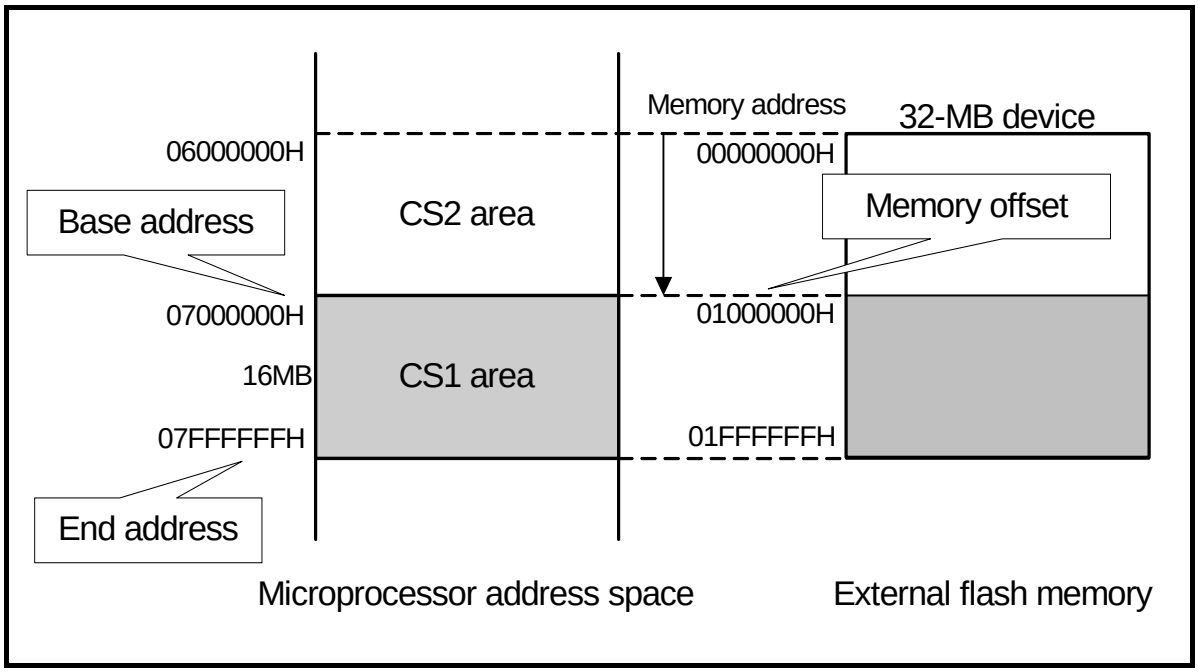
Figure 3.4 Example of Setting the End Address

If the end address exceeds the CS boundary, see Section 3.3.3, for details on how to set.

3.3.3 Memory Offset

When using large-capacity flash memory that may take up two or more of consecutive external CS areas of the microprocessor, you need to prepare separate USD files, one for each CS area.

In such a case, it is necessary to set a memory offset.



* Example for the case where the first half of 32-MB flash memory is mapped to the CS2 area and the latter half is mapped to the CS1 area by the RX610
* An external circuit is required that will input CS2# & CS1# to the CE# pin of the external flash and output a 0 to the most significant address A24 when CS2# = low or a 1 when CS1# = low.

Figure 3.5 Example of Using a Memory Offset

In the above example, CS2 and CS1 need to be set as follows:

■ CS2 area

[Base Address]: "06000000"H [End Address]: "06FFFFFF"H

[Memory Offset]: "0"H

■ CS1 area

[Base Address]: "07000000"H [End Address]: "07FFFFFF"H

[Memory Offset]: "01000000"H

To the CS2 area, map the first half of the flash memory.

Change the initial value of the end address from 07FFFFFFH to the end address of the CS2 area, 06FFFFFFH.

To the CS1 area, map the latter half of the flash memory.

For the memory offset, set 01000000H, an amount equal to the size of the CS2 area.

The end address is automatically changed from 08FFFFFFH to 07FFFFFFH simultaneously as the memory offset changes.

3.3.4 Mapping Information Window

This window shows the mapping start address and size per sector.

The content of this window is updated in real time according to the input values of [Base Address], [End Address], and [Memory Offset].

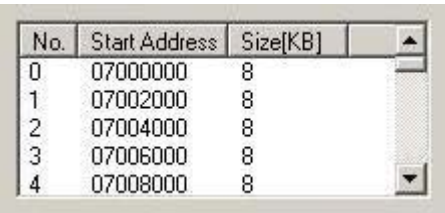


Figure 3.6 Mapping Information Window

3.3.5 Pre-Download Execution Script

Immediately before a download process, it is possible to execute a command script of HEW.

Here, specify the script file to be executed on that occasion.

By writing the external bus controller settings, etc. needed for accessing the external flash in a script beforehand, you can save the time that might otherwise be taken for various settings before executing a download.

If a download is executed while the CPU clock remains set to a low speed, it is possible that processing will take an extremely long time or will not terminate normally. We recommend that a setting to speed up the CPU clock be written in this script.

For details about the commands usable in a script file, see Section 4.3, "About the Script Command".

3.3.6 Post-Download Execution Script

Immediately after a download process, it is possible to execute a command script of HEW.

Here, specify the script file to be executed on that occasion.

By writing the external bus controller setting write-back processes, etc. in a script beforehand, you can save the time that might otherwise be taken for various settings after executing a download.

For details about the commands usable in a script file, see Section 4.3, "About the Script Command".

3.4 Work RAM

Set up the work RAM as needed for program to flash memory.

The work RAM data is automatically saved to the stack before a download is executed and automatically restored from the stack after the download is completed.

3.4.1 Base Address

Set the mapping start address of the work RAM.

Specify the internal RAM or one of RAMs connected to the external bus (hereafter called an external RAM).

3.4.2 Size

Displayed here is the necessary size of the work RAM that is automatically calculated.

3.4.3 External RAM

When you use an external RAM as the work RAM, check this checkbox.

3.4.4 Width of Access

Specify the width of access of the external RAM.

3.4.5 External RAM Pre-Use Execution Script

If you've chosen to use an external RAM, it is possible to automatically execute a command script of HEW immediately before use of the work RAM begins.

Here, specify the script file to be executed on that occasion.

By writing the external bus controller settings, etc. needed for accessing the external RAM in a script beforehand, you can save the time that might otherwise be taken for various settings before executing a download.

For details about the commands usable in a script file, see Section 4.3, "About the Script Command".

3.4.6 External RAM Post-Use Execution Script

If you've chosen to use an external RAM, it is possible to automatically execute a command script of HEW immediately after use of the work RAM is finished.

Here, specify the script file to be executed on that occasion.

By writing the external bus controller setting write-back processes, etc. in a script beforehand, you can save the time that might otherwise be taken for various settings after executing a download.

For details about the commands usable in a script file, see Section 4.3, "About the Script Command".

3.5 Comment Column

You can enter any character string as a comment here.

The comment you enter is recorded in the USD file.

3.6 Referring to the USD File

To re-edit the USD file you've created or create a new USD file based on the USD file you've created, specify the source USD file here that you want to edit or from which to create.

3.7 Save USD File

This button saves the USD file.

If the input content of the file is incomplete or erroneous, an error message is output and the save operation is canceled. In that case, correct the content according to the instructions of the error message.

4. Precautions

4.1 About the Generation of USD Files

The USD files should be created following the rules described below.

1. Basically, create one USD file per flash memory device.
   However, flash memory devices are used in parallel-connected form as in an 8-bit × 2, 8-bit × 4, or 16-bit × 2 form, handle the whole as one flash memory device and create one USD file for those devices.

2. For a type of flash memory device that takes up two or more external CS areas, create USD files separately, one for each CS area.
   (For details, see your emulator software manual.)
   In that case, use a memory offset as you create a USD file for each CS area.

4.2 When Using the USD File in Another PC

The script file you specify on the USD file creation tab is saved in the USD file in the form "absolute file path + file name."

Therefore, if you want to use an existing USD file that has had a script file specified in another PC, you need to edit the path to the script file to make it suitable for the PC environment you use.

Here is the edit process.

1. Install EFE in the PC you use.
2. Launch EFE and open the USD file creating tab.
3. Use the [Load USD File...] button to load the USD file you've obtained.
4. In the script specification menu, edit the destination into which the script file is to be loaded.
5. Click the [Save USD File...] button, and a new USD file is created.

4.3 About the Script Command

On the USD file creation tab, you can specify one of the following script files:

- Pre-download execution script
- Post-download execution script
- External RAM pre-use execution script
- External RAM post-use execution script

In the above script files, the following command format is supported:

■ memory_fill command

Command format: MF <start> <end> <data> [<mode>]

start: start address

end: end address

data: fill data

mode: [BYTE][WORD][LONG]; if omitted, [BYTE] is assumed

Note:

Only part of the options of the memory_fill command usable in the command line window of HEW are supported. If other options than those given above are specified, device operation cannot be guaranteed.

External Flash Definition Editor
User's Manual

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